



(12) **CORRECTED EUROPEAN PATENT APPLICATION**  
published in accordance with Art. 153(4) EPC

(15) Correction information:  
**Corrected version no 1 (W1 A1)**  
**Corrections, see**  
**Bibliography INID code(s) 71**

(51) Int Cl.:  
**C30B 29/04** (2006.01) **C23C 16/56** (2006.01)  
**C25F 3/02** (2006.01)

(48) Corrigendum issued on:  
**22.07.2009 Bulletin 2009/30**

(86) International application number:  
**PCT/JP2007/067023**

(43) Date of publication:  
**13.05.2009 Bulletin 2009/20**

(87) International publication number:  
**WO 2008/029736 (13.03.2008 Gazette 2008/11)**

(21) Application number: **07806496.1**

(22) Date of filing: **31.08.2007**

(84) Designated Contracting States:  
**DE FR GB**

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(30) Priority: **04.09.2006 JP 2006238402**

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(54) **METHOD FOR SEPARATING SURFACE LAYER OR GROWTH LAYER OF DIAMOND**

(57) The present invention provides a method for separating a surface layer of a diamond, which comprises implanting ions into a diamond to form a non-diamond layer near a surface of the diamond; and etching the non-diamond layer in the diamond by applying an alternating-current voltage across electrodes in an electrolytic solution; and a method for separating a grown layer of a diamond, which further comprises the step of growing a diamond by a vapor-phase synthesis method, after forming a non-diamond layer according to the above-described method.

The invention is applicable to various single-crystal and polycrystal diamonds. More specifically, even with a large single-crystal diamond, a portion of the single-crystal diamond can be efficiently separated in a reusable form in a relatively short period of time.

FIG.1

